



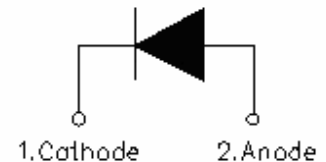
LURF1060 ULTRAFAST PLASTIC RECTIFIER

Features:

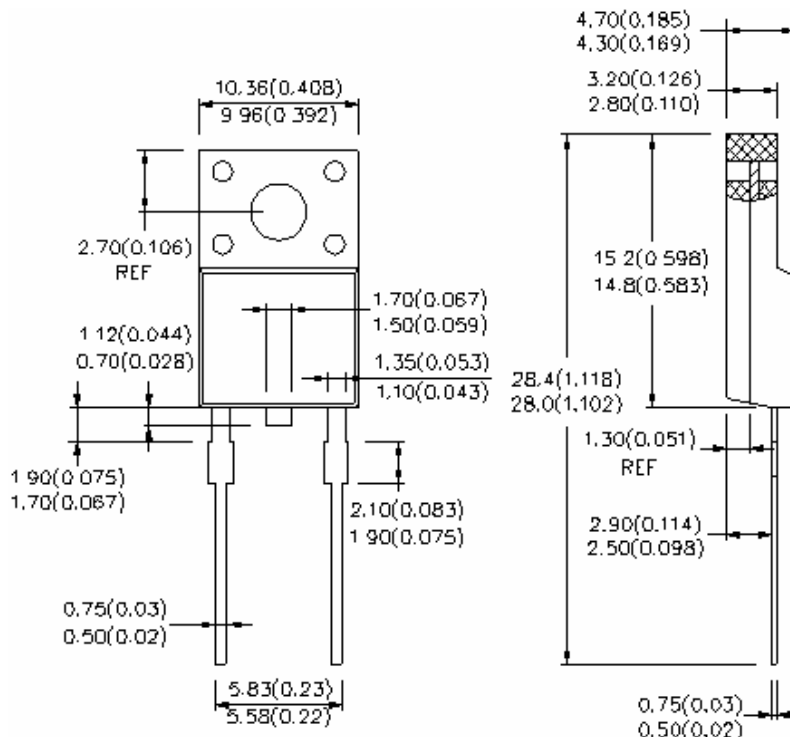
- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-0
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data:

- Case: Molded Plastic
- Terminals: Plated Leads, Solderable per MIL-STD-202, Method 208
- Weight: 1.6 grams (approx.)
- Marking: Type Number
- Mounting Position: Any



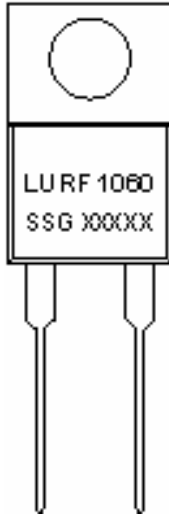
Mechanical Dimensions: In Inches / mm



ITO-220AC



Marking Diagram:



Where XXXXX is YYWWL

LUR = Device Type
F = Package type
10 = Forward Current (10A)
60 = Reverse Voltage (600V)
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

| Device | Package | Shipping |
|----------|------------------------|---------------|
| LURF1060 | ITO-220AC (Pb-Free) | 50 pcs / tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|-------------|---|------|-------|
| Peak Inverse Voltage | V_{RWM} | - | 600 | V |
| Max. Average Forward | $I_{F(AV)}$ | 50% duty cycle @ $T_c = 100^\circ\text{C}$ rectangular wave form | 10 | A |
| Max. Peak One Cycle Non-Repetitive Surge Current | I_{FSM} | 8.3 ms, half Sine pulse | 180 | A |



Electrical Characteristics:

| Characteristics | Symbol | Condition | Max. | Units |
|----------------------------|----------|---|------|---------------|
| Max. Forward Voltage Drop | V_{F1} | @ 10A, Pulse, $T_J = 25^\circ\text{C}$ | 2.2 | V |
| | V_{F2} | @ 10 A, Pulse, $T_J = 100^\circ\text{C}$ | 2.0 | V |
| Max. Reverse Current | I_{R1} | @ $V_R = \text{rated VR}$ $T_J = 25^\circ\text{C}$ | 5 | μA |
| | I_{R2} | @ $V_R = \text{rated VR}$ $T_J = 100^\circ\text{C}$ | 50 | μA |
| Max. Reverse Recovery Time | t_{rr} | $I_F=10\text{A}$, $di/dt=50\text{A}/\text{s}$, 25°C | 50 | ns |

* Pulse Width < 300 μs , Duty Cycle <2%
Measured lead to lead 5 mm from package body

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|-----------------|--------------|---------------|---------------------------|
| Max. Junction Temperature | T_J | - | -55 to +150 | $^\circ\text{C}$ |
| Max. Storage Temperature | T_{stg} | - | -55 to +150 | $^\circ\text{C}$ |
| Maximum Thermal Resistance Junction to Case | $R_{\theta JC}$ | DC operation | 4 | $^\circ\text{C}/\text{W}$ |
| Approximate Weight | wt | - | 1.6 | g |
| Case Style | | ITO-220AC | | |

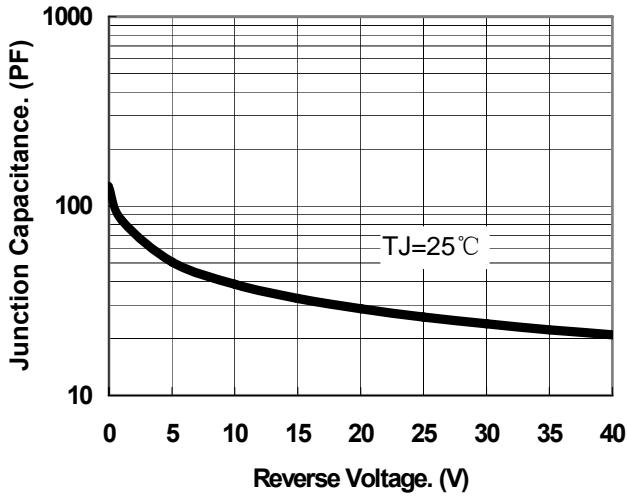


Fig.1-Typical Junction Capacitance

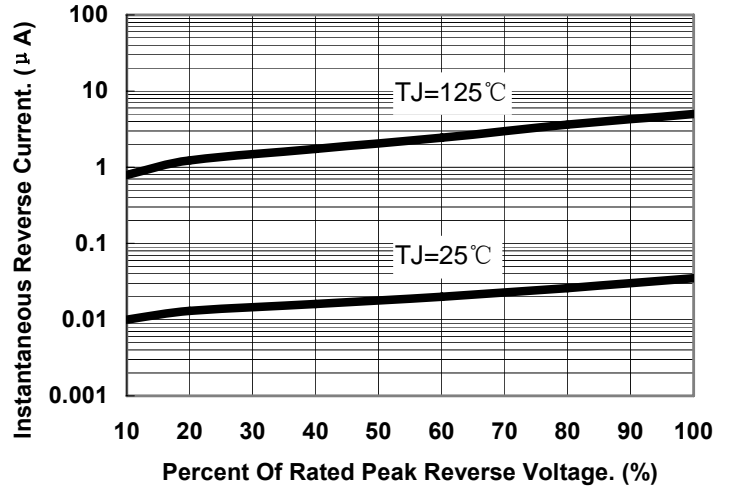


Fig.2-Typical Reverse Characteristics

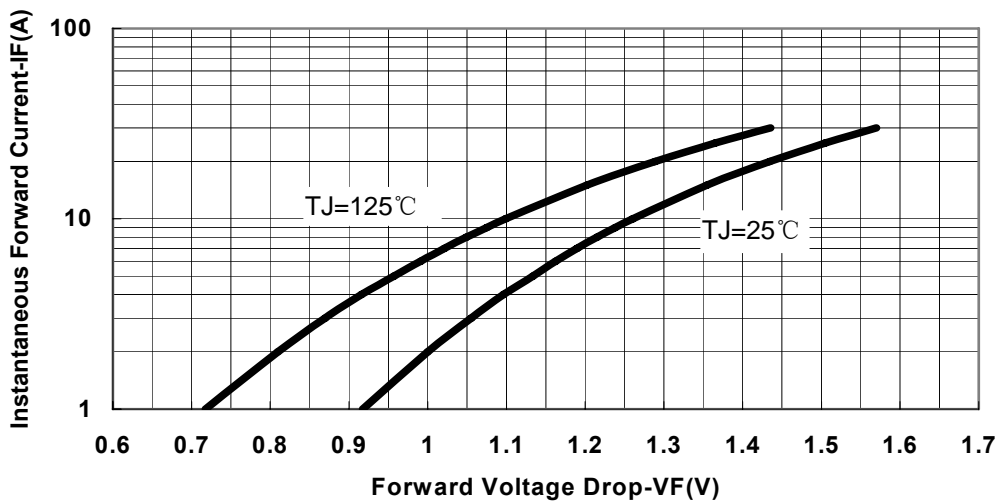


Fig.3-Typical Forward Voltage Drop Characteristics



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